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Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	120
Number of Logic Elements/Cells	1200
Total RAM Bits	24576
Number of I/O	-
Number of Gates	113000
Voltage - Supply	1.71V ~ 1.89V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	256-LBGA
Supplier Device Package	256-BGA (27x27)
Purchase URL	https://www.e-xfl.com/product-detail/intel/ep20k30efc256-2

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Each LAB contains dedicated logic for driving control signals to its LEs and ESBs. The control signals include clock, clock enable, asynchronous clear, asynchronous preset, asynchronous load, synchronous clear, and synchronous load signals. A maximum of six control signals can be used at a time. Although synchronous load and clear signals are generally used when implementing counters, they can also be used with other functions.

Each LAB can use two clocks and two clock enable signals. Each LAB's clock and clock enable signals are linked (e.g., any LE in a particular LAB using CLK1 will also use CLKENA1). LEs with the same clock but different clock enable signals either use both clock signals in one LAB or are placed into separate LABs.

If both the rising and falling edges of a clock are used in a LAB, both LAB-wide clock signals are used.

The LAB-wide control signals can be generated from the LAB local interconnect, global signals, and dedicated clock pins. The inherent low skew of the FastTrack Interconnect enables it to be used for clock distribution. Figure 4 shows the LAB control signal generation circuit.

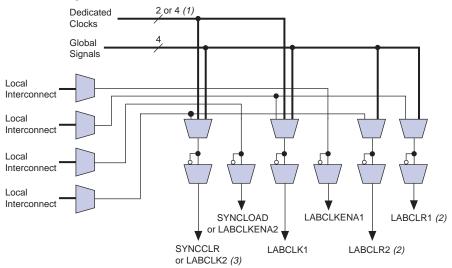


Figure 4. LAB Control Signal Generation

Notes to Figure 4:

- (1) APEX 20KE devices have four dedicated clocks.
- (2) The LABCLR1 and LABCLR2 signals also control asynchronous load and asynchronous preset for LEs within the LAB.
- (3) The SYNCCLR signal can be generated by the local interconnect or global signals.

LE Operating Modes

The APEX 20K LE can operate in one of the following three modes:

- Normal mode
- Arithmetic mode
- Counter mode

Each mode uses LE resources differently. In each mode, seven available inputs to the LE—the four data inputs from the LAB local interconnect, the feedback from the programmable register, and the carry-in and cascade-in from the previous LE—are directed to different destinations to implement the desired logic function. LAB-wide signals provide clock, asynchronous clear, asynchronous preset, asynchronous load, synchronous clear, synchronous load, and clock enable control for the register. These LAB-wide signals are available in all LE modes.

The Quartus II software, in conjunction with parameterized functions such as LPM and DesignWare functions, automatically chooses the appropriate mode for common functions such as counters, adders, and multipliers. If required, the designer can also create special-purpose functions that specify which LE operating mode to use for optimal performance. Figure 8 shows the LE operating modes.

Figure 11 shows the intersection of a row and column interconnect, and how these forms of interconnects and LEs drive each other.

Row Interconnect

MegaLAB Interconnect

Column Interconnect

Interconnect

Figure 11. Driving the FastTrack Interconnect

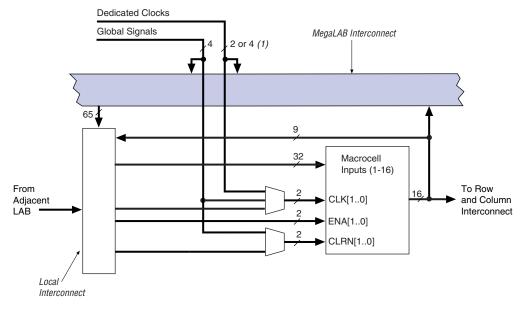
APEX 20KE devices include an enhanced interconnect structure for faster routing of input signals with high fan-out. Column I/O pins can drive the FastRow interconnect, which routes signals directly into the local interconnect without having to drive through the MegaLAB interconnect. FastRow lines traverse two MegaLAB structures. Also, these pins can drive the local interconnect directly for fast setup times. On EP20K300E and larger devices, the FastRow interconnect drives the two MegaLABs in the top left corner, the two MegaLABs in the top right corner, the two MegaLABS in the bottom left corner, and the two MegaLABs in the bottom right corner. On EP20K200E and smaller devices, FastRow interconnect drives the two MegaLABs on the top and the two MegaLABs on the bottom of the device. On all devices, the FastRow interconnect drives all local interconnect in the appropriate MegaLABs except the local interconnect on the side of the MegaLAB opposite the ESB. Pins using the FastRow interconnect achieve a faster set-up time, as the signal does not need to use a MegaLAB interconnect line to reach the destination LE. Figure 12 shows the FastRow interconnect.

Select Vertical I/O Pins IOE IOE FastRow Interconnect IOE IOE Drive Local Interconnect FastRow Drives Local Interconnect and FastRow Interconnect in Two MegaLAB Structures Interconnect Local Interconnect LEs MegaLAB MegaLAB *LABs*

Figure 12. APEX 20KE FastRow Interconnect

Table 9 summarizes how various elements of the APEX 20K architecture drive each other.

Figure 13. Product-Term Logic in ESB



Note to Figure 13:

(1) APEX 20KE devices have four dedicated clocks.

Macrocells

APEX 20K macrocells can be configured individually for either sequential or combinatorial logic operation. The macrocell consists of three functional blocks: the logic array, the product-term select matrix, and the programmable register.

Combinatorial logic is implemented in the product terms. The product-term select matrix allocates these product terms for use as either primary logic inputs (to the OR and XOR gates) to implement combinatorial functions, or as parallel expanders to be used to increase the logic available to another macrocell. One product term can be inverted; the Quartus II software uses this feature to perform DeMorgan's inversion for more efficient implementation of wide OR functions. The Quartus II software Compiler can use a NOT-gate push-back technique to emulate an asynchronous preset. Figure 14 shows the APEX 20K macrocell.

The programmable register also supports an asynchronous clear function. Within the ESB, two asynchronous clears are generated from global signals and the local interconnect. Each macrocell can either choose between the two asynchronous clear signals or choose to not be cleared. Either of the two clear signals can be inverted within the ESB. Figure 15 shows the ESB control logic when implementing product-terms.

Dedicated Clocks Global Signals Local Interconnect Local Interconnect Local Interconnect Local Interconnect CLR1 CLKENA2 CLK1 CLKENA1 CLR₂

Figure 15. ESB Product-Term Mode Control Logic

Note to Figure 15:

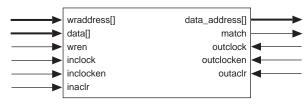
(1) APEX 20KE devices have four dedicated clocks.

Parallel Expanders

Parallel expanders are unused product terms that can be allocated to a neighboring macrocell to implement fast, complex logic functions. Parallel expanders allow up to 32 product terms to feed the macrocell OR logic directly, with two product terms provided by the macrocell and 30 parallel expanders provided by the neighboring macrocells in the ESB.

The Quartus II software Compiler can allocate up to 15 sets of up to two parallel expanders per set to the macrocells automatically. Each set of two parallel expanders incurs a small, incremental timing delay. Figure 16 shows the APEX 20K parallel expanders.

Figure 23. APEX 20KE CAM Block Diagram



CAM can be used in any application requiring high-speed searches, such as networking, communications, data compression, and cache management.

The APEX 20KE on-chip CAM provides faster system performance than traditional discrete CAM. Integrating CAM and logic into the APEX 20KE device eliminates off-chip and on-chip delays, improving system performance.

When in CAM mode, the ESB implements 32-word, 32-bit CAM. Wider or deeper CAM can be implemented by combining multiple CAMs with some ancillary logic implemented in LEs. The Quartus II software combines ESBs and LEs automatically to create larger CAMs.

CAM supports writing "don't care" bits into words of the memory. The "don't-care" bit can be used as a mask for CAM comparisons; any bit set to "don't-care" has no effect on matches.

The output of the CAM can be encoded or unencoded. When encoded, the ESB outputs an encoded address of the data's location. For instance, if the data is located in address 12, the ESB output is 12. When unencoded, the ESB uses its 16 outputs to show the location of the data over two clock cycles. In this case, if the data is located in address 12, the 12th output line goes high. When using unencoded outputs, two clock cycles are required to read the output because a 16-bit output bus is used to show the status of 32 words.

The encoded output is better suited for designs that ensure duplicate data is not written into the CAM. If duplicate data is written into two locations, the CAM's output will be incorrect. If the CAM may contain duplicate data, the unencoded output is a better solution; CAM with unencoded outputs can distinguish multiple data locations.

CAM can be pre-loaded with data during configuration, or it can be written during system operation. In most cases, two clock cycles are required to write each word into CAM. When "don't-care" bits are used, a third clock cycle is required.

Each IOE drives a row, column, MegaLAB, or local interconnect when used as an input or bidirectional pin. A row IOE can drive a local, MegaLAB, row, and column interconnect; a column IOE can drive the column interconnect. Figure 27 shows how a row IOE connects to the interconnect.

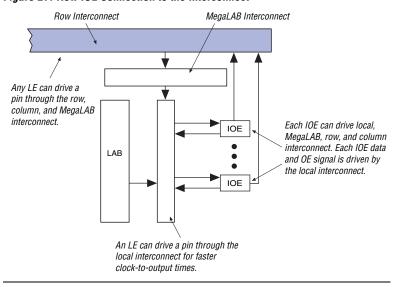


Figure 27. Row IOE Connection to the Interconnect

Table 2	6. APEX 20K 5.0-V Tolerant L	Device Capacitance Notes (2), (14)			
Symbol	Parameter	Conditions	Min	Max	Unit
C _{IN}	Input capacitance	V _{IN} = 0 V, f = 1.0 MHz		8	pF
C _{INCLK}	Input capacitance on dedicated clock pin	V _{IN} = 0 V, f = 1.0 MHz		12	pF
C _{OUT}	Output capacitance	V _{OUT} = 0 V, f = 1.0 MHz		8	pF

Notes to Tables 23 through 26:

- (1) See the Operating Requirements for Altera Devices Data Sheet.
- (2) All APEX 20K devices are 5.0-V tolerant.
- (3) Minimum DC input is -0.5 V. During transitions, the inputs may undershoot to -2.0 V or overshoot to 5.75 V for input currents less than 100 mA and periods shorter than 20 ns.
- (4) Numbers in parentheses are for industrial-temperature-range devices.
- (5) Maximum V_{CC} rise time is 100 ms, and V_{CC} must rise monotonically.
- (6) All pins, including dedicated inputs, clock I/O, and JTAG pins, may be driven before V_{CCINT} and V_{CCIO} are powered.
- (7) Typical values are for $T_A = 25^{\circ}$ C, $V_{CCINT} = 2.5$ V, and $V_{CCIO} = 2.5$ or 3.3 V.
- (8) These values are specified in the APEX 20K device recommended operating conditions, shown in Table 26 on page 62.
- (9) The APEX 20K input buffers are compatible with 2.5-V and 3.3-V (LVTTL and LVCMOS) signals. Additionally, the input buffers are 3.3-V PCI compliant when V_{CCIO} and V_{CCINT} meet the relationship shown in Figure 33 on page 68.
- (10) The I_{OH} parameter refers to high-level TTL, PCI or CMOS output current.
- (11) The I_{OL} parameter refers to low-level TTL, PCI, or CMOS output current. This parameter applies to open-drain pins as well as output pins.
- (12) This value is specified for normal device operation. The value may vary during power-up.
- (13) Pin pull-up resistance values will be lower if an external source drives the pin higher than V_{CCIO} .
- (14) Capacitance is sample-tested only.

Tables 27 through 30 provide information on absolute maximum ratings, recommended operating conditions, DC operating conditions, and capacitance for 1.8-V APEX 20KE devices.

Table 2	Table 27. APEX 20KE Device Absolute Maximum Ratings Note (1)							
Symbol	Parameter	Conditions	Min	Max	Unit			
V _{CCINT}	Supply voltage	With respect to ground (2)	-0.5	2.5	V			
V_{CCIO}			-0.5	4.6	٧			
V _I	DC input voltage		-0.5	4.6	V			
I _{OUT}	DC output current, per pin		-25	25	mA			
T _{STG}	Storage temperature	No bias	-65	150	° C			
T _{AMB}	Ambient temperature	Under bias	-65	135	° C			
TJ	Junction temperature	PQFP, RQFP, TQFP, and BGA packages, under bias		135	° C			
		Ceramic PGA packages, under bias		150	° C			

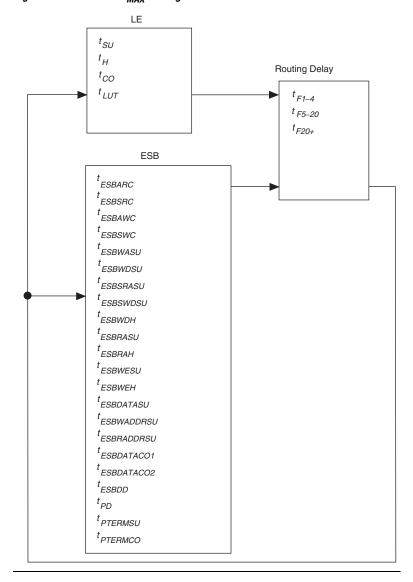


Figure 37. APEX 20KE f_{MAX} Timing Model

Tables 40 through 42 show the $f_{\mbox{\scriptsize MAX}}$ timing parameters for EP20K100, EP20K200, and EP20K400 APEX 20K devices.

Symbol	-1 Spee	d Grade	-2 Spee	d Grade	-3 Speed Grade		Units	
	Min	Max	Min	Max	Min	Max		
t _{SU}	0.5		0.6		0.8		ns	
t _H	0.7		0.8		1.0		ns	
t _{CO}		0.3		0.4		0.5	ns	
t _{LUT}		0.8		1.0		1.3	ns	
t _{ESBRC}		1.7		2.1		2.4	ns	
t _{ESBWC}		5.7		6.9		8.1	ns	
t _{ESBWESU}	3.3		3.9		4.6		ns	
t _{ESBDATASU}	2.2		2.7		3.1		ns	
t _{ESBDATAH}	0.6		0.8		0.9		ns	
t _{ESBADDRSU}	2.4		2.9		3.3		ns	
t _{ESBDATACO1}		1.3		1.6		1.8	ns	
t _{ESBDATACO2}		2.6		3.1		3.6	ns	
t _{ESBDD}		2.5		3.3		3.6	ns	
t _{PD}		2.5		3.0		3.6	ns	
t _{PTERMSU}	2.3		2.6		3.2		ns	
t _{PTERMCO}		1.5		1.8		2.1	ns	
t _{F1-4}		0.5		0.6		0.7	ns	
t _{F5-20}		1.6		1.7		1.8	ns	
t _{F20+}		2.2		2.2		2.3	ns	
t _{CH}	2.0		2.5		3.0		ns	
t _{CL}	2.0		2.5		3.0		ns	
t _{CLRP}	0.3		0.4		0.4		ns	
t _{PREP}	0.5		0.5		0.5		ns	
t _{ESBCH}	2.0		2.5		3.0		ns	
t _{ESBCL}	2.0		2.5		3.0		ns	
t _{ESBWP}	1.6		1.9		2.2		ns	
t _{ESBRP}	1.0		1.3		1.4	_	ns	

Symbol	-1 Spee	d Grade	-2 Spee	ed Grade -3 Speed Grade		-3 Speed Grade	
	Min	Max	Min	Max	Min	Max	
t _{INSUBIDIR} (1)	1.9		2.3		2.6		ns
t _{INHBIDIR} (1)	0.0		0.0		0.0		ns
t _{OUTCOBIDIR} (1)	2.0	4.6	2.0	5.6	2.0	6.8	ns
t _{XZBIDIR} (1)		5.0		5.9		6.9	ns
t _{ZXBIDIR} (1)		5.0		5.9		6.9	ns
t _{INSUBIDIR} (2)	1.1		1.2		-		ns
t _{INHBIDIR} (2)	0.0		0.0		-		ns
t _{OUTCOBIDIR} (2)	0.5	2.7	0.5	3.1	-	_	ns
t _{XZBIDIR} (2)		4.3		5.0		_	ns
t _{ZXBIDIR} (2)		4.3		5.0		_	ns

Table 47. EP2	Table 47. EP20K400 External Timing Parameters							
Symbol	-1 Spee	d Grade	-2 Spec	ed Grade	-3 Spee	Unit		
	Min	Max	Min	Max	Min	Max	1	
t _{INSU} (1)	1.4		1.8		2.0		ns	
t _{INH} (1)	0.0		0.0		0.0		ns	
t _{OUTCO} (1)	2.0	4.9	2.0	6.1	2.0	7.0	ns	
t _{INSU} (2)	0.4		1.0		-		ns	
t _{INH} (2)	0.0		0.0		_		ns	
t _{OUTCO} (2)	0.5	3.1	0.5	4.1	_	_	ns	

Table 48. EP20K400 External Bidirectional Ti	imina	Parameters 4 8 1
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Symbol	-1 Spee	d Grade	-2 Spee	d Grade	-3 Spe	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{INSUBIDIR} (1)	1.4		1.8		2.0		ns
t _{INHBIDIR} (1)	0.0		0.0		0.0		ns
t _{OUTCOBIDIR} (1)	2.0	4.9	2.0	6.1	2.0	7.0	ns
t _{XZBIDIR} (1)		7.3		8.9		10.3	ns
t _{ZXBIDIR} (1)		7.3		8.9		10.3	ns
t _{INSUBIDIR} (2)	0.5		1.0		-		ns
t _{INHBIDIR} (2)	0.0		0.0		-		ns
toutcobidir (2)	0.5	3.1	0.5	4.1	-	-	ns
t _{XZBIDIR} (2)		6.2		7.6		-	ns
t _{ZXBIDIR} (2)		6.2		7.6		_	ns

Notes to Tables 43 through 48:

- (1) This parameter is measured without using ClockLock or ClockBoost circuits.
- (2) This parameter is measured using ClockLock or ClockBoost circuits.

Tables 49 through 54 describe f_{MAX} LE Timing Microparameters, f_{MAX} ESB Timing Microparameters, f_{MAX} Routing Delays, Minimum Pulse Width Timing Parameters, External Timing Parameters, and External Bidirectional Timing Parameters for EP20K30E APEX 20KE devices.

Table 49. EP20K30E f _{MAX} LE Timing Microparameters									
Symbol	_	1	-	2	-;	3	Unit		
	Min	Max	Min	Max	Min	Max	1		
t _{SU}	0.01		0.02		0.02		ns		
t _H	0.11		0.16		0.23		ns		
t _{CO}		0.32		0.45		0.67	ns		
t _{LUT}		0.85		1.20		1.77	ns		

Tables 55 through 60 describe f_{MAX} LE Timing Microparameters, f_{MAX} ESB Timing Microparameters, f_{MAX} Routing Delays, Minimum Pulse Width Timing Parameters, External Timing Parameters, and External Bidirectional Timing Parameters for EP20K60E APEX 20KE devices.

Table 55. EP2	Table 55. EP20K60E f _{MAX} LE Timing Microparameters									
Symbol	-	1	,	-2	-	-3				
	Min	Max	Min	Max	Min	Max]			
t _{SU}	0.17		0.15		0.16		ns			
t _H	0.32		0.33		0.39		ns			
t _{CO}		0.29		0.40		0.60	ns			
t _{LUT}		0.77		1.07		1.59	ns			

Symbol	-	1	-	2	-3	3	Unit
	Min	Max	Min	Max	Min	Max	
t _{CH}	2.00		2.00		2.00		ns
t _{CL}	2.00		2.00		2.00		ns
t _{CLRP}	0.20		0.20		0.20		ns
t _{PREP}	0.20		0.20		0.20		ns
t _{ESBCH}	2.00		2.00		2.00		ns
t _{ESBCL}	2.00		2.00		2.00		ns
t _{ESBWP}	1.29		1.53		1.66		ns
t _{ESBRP}	1.11		1.29		1.41		ns

Symbol	-	1	-	-2	-3	}	Unit
	Min	Max	Min	Max	Min	Max	7
t _{INSU}	2.23		2.32		2.43		ns
t _{INH}	0.00		0.00		0.00		ns
t _{outco}	2.00	4.86	2.00	5.35	2.00	5.84	ns
t _{INSUPLL}	1.58		1.66		-		ns
t _{INHPLL}	0.00		0.00		=		ns
t _{OUTCOPLL}	0.50	2.96	0.50	3.29	-	-	ns

Symbol	-1		-2		-3		Unit
	Min	Max	Min	Max	Min	Max	
t _{INSUBIDIR}	2.74		2.96		3.19		ns
t _{INHBIDIR}	0.00		0.00		0.00		ns
t _{OUTCOBIDIR}	2.00	4.86	2.00	5.35	2.00	5.84	ns
t _{XZBIDIR}		5.00		5.48		5.89	ns
t _{ZXBIDIR}		5.00		5.48		5.89	ns
t _{INSUBIDIRPLL}	4.64		5.03		-		ns
t _{INHBIDIRPLL}	0.00		0.00		-		ns
t _{OUTCOBIDIRPLL}	0.50	2.96	0.50	3.29	-	-	ns
t _{XZBIDIRPLL}		3.10		3.42		-	ns
tzxbidirpll		3.10		3.42		-	ns

Symbol	-1		-	2	-	Unit	
	Min	Max	Min	Max	Min	Max	
t _{INSUBIDIR}	2.86		3.24		3.54		ns
t _{INHBIDIR}	0.00		0.00		0.00		ns
t _{OUTCOBIDIR}	2.00	5.07	2.00	5.59	2.00	6.13	ns
t _{XZBIDIR}		7.43		8.23		8.58	ns
t _{ZXBIDIR}		7.43		8.23		8.58	ns
t _{INSUBIDIRPLL}	4.93		5.48		-		ns
t _{INHBIDIRPLL}	0.00		0.00		-		ns
toutcobidirpll	0.50	3.00	0.50	3.35	-	-	ns
t _{XZBIDIRPLL}		5.36		5.99		-	ns
t _{ZXBIDIRPLL}		5.36		5.99		-	ns

Tables 73 through 78 describe f_{MAX} LE Timing Microparameters, f_{MAX} ESB Timing Microparameters, f_{MAX} Routing Delays, Minimum Pulse Width Timing Parameters, External Timing Parameters, and External Bidirectional Timing Parameters for EP20K200E APEX 20KE devices.

Table 73. EP2	Table 73. EP20K200E f _{MAX} LE Timing Microparameters												
Symbol	-	1		-2	-3	-3							
	Min	Max	Min	Max	Min	Max							
t _{SU}	0.23		0.24		0.26		ns						
t _H	0.23		0.24		0.26		ns						
t _{CO}		0.26		0.31		0.36	ns						
t _{LUT}		0.70		0.90		1.14	ns						

Symbol	-	1	-	2	-;	3	Unit
	Min	Max	Min	Max	Min	Max	
t _{ESBARC}		1.68		2.06		2.24	ns
t _{ESBSRC}		2.27		2.77		3.18	ns
t _{ESBAWC}		3.10		3.86		4.50	ns
t _{ESBSWC}		2.90		3.67		4.21	ns
t _{ESBWASU}	0.55		0.67		0.74		ns
t _{ESBWAH}	0.36		0.46		0.48		ns
t _{ESBWDSU}	0.69		0.83		0.95		ns
t _{ESBWDH}	0.36		0.46		0.48		ns
t _{ESBRASU}	1.61		1.90		2.09		ns
t _{ESBRAH}	0.00		0.00		0.01		ns
t _{ESBWESU}	1.42		1.71		2.01		ns
t _{ESBWEH}	0.00		0.00		0.00		ns
t _{ESBDATASU}	-0.06		-0.07		0.05		ns
t _{ESBDATAH}	0.13		0.13		0.13		ns
t _{ESBWADDRSU}	0.11		0.13		0.31		ns
t _{ESBRADDRSU}	0.18		0.23		0.39		ns
t _{ESBDATACO1}		1.09		1.35		1.51	ns
t _{ESBDATACO2}		2.19		2.75		3.22	ns
t _{ESBDD}		2.75		3.41		4.03	ns
t _{PD}		1.58		1.97		2.33	ns
t _{PTERMSU}	1.00		1.22		1.51		ns
t _{PTERMCO}		1.10		1.37		1.09	ns

Table 75. EP2	0K200E f _{MAX} 1	Routing Delay	s				
Symbol	-	1		-2	-:	-3	Unit
	Min	Max	Min	Max	Min	Max	
t _{F1-4}		0.25		0.27		0.29	ns
t _{F5-20}		1.02		1.20		1.41	ns
t _{F20+}		1.99		2.23		2.53	ns

Symbol	-1		-	2	-	Unit	
	Min	Max	Min	Max	Min	Max	
t _{INSUBIDIR}	2.81		3.19		3.54		ns
t _{INHBIDIR}	0.00		0.00		0.00		ns
toutcobidir	2.00	5.12	2.00	5.62	2.00	6.11	ns
t _{XZBIDIR}		7.51		8.32		8.67	ns
tzxbidir		7.51		8.32		8.67	ns
t _{INSUBIDIRPLL}	3.30		3.64		-		ns
t _{INHBIDIRPLL}	0.00		0.00		-		ns
toutcobidirpll	0.50	3.01	0.50	3.36	-	-	ns
t _{XZBIDIRPLL}		5.40		6.05		-	ns
tzxbidirpll		5.40		6.05		-	ns

Tables 79 through 84 describe f_{MAX} LE Timing Microparameters, f_{MAX} ESB Timing Microparameters, f_{MAX} Routing Delays, Minimum Pulse Width Timing Parameters, External Timing Parameters, and External Bidirectional Timing Parameters for EP20K300E APEX 20KE devices.

Table 79. EP20K300E f _{MAX} LE Timing Microparameters												
Symbol	-	-1		-2		3	Unit					
	Min	Max	Min	Max	Min	Max						
t _{SU}	0.16		0.17		0.18		ns					
t _H	0.31		0.33		0.38		ns					
t _{CO}		0.28		0.38		0.51	ns					
t _{LUT}		0.79		1.07		1.43	ns					

Symbol	-	1	-	-2		3	Unit
	Min	Max	Min	Max	Min	Max	
t _{ESBARC}		1.79		2.44		3.25	ns
t _{ESBSRC}		2.40		3.12		4.01	ns
t _{ESBAWC}		3.41		4.65		6.20	ns
t _{ESBSWC}		3.68		4.68		5.93	ns
t _{ESBWASU}	1.55		2.12		2.83		ns
t _{ESBWAH}	0.00		0.00		0.00		ns
t _{ESBWDSU}	1.71		2.33		3.11		ns
t _{ESBWDH}	0.00		0.00		0.00		ns
t _{ESBRASU}	1.72		2.34		3.13		ns
t _{ESBRAH}	0.00		0.00		0.00		ns
t _{ESBWESU}	1.63		2.36		3.28		ns
t _{ESBWEH}	0.00		0.00		0.00		ns
t _{ESBDATASU}	0.07		0.39		0.80		ns
t _{ESBDATAH}	0.13		0.13		0.13		ns
t _{ESBWADDRSU}	0.27		0.67		1.17		ns
t _{ESBRADDRSU}	0.34		0.75		1.28		ns
t _{ESBDATACO1}		1.03		1.20		1.40	ns
t _{ESBDATACO2}		2.33		3.18		4.24	ns
t _{ESBDD}		3.41		4.65		6.20	ns
t _{PD}		1.68		2.29		3.06	ns
t _{PTERMSU}	0.96		1.48		2.14		ns
t _{PTERMCO}		1.05		1.22		1.42	ns

Table 81. EP2	OK300E f _{MAX} I	Routing Delay	s				
Symbol	-	1		2	-	Unit	
	Min	Max	Min	Max	Min	Max	1
t _{F1-4}		0.22		0.24		0.26	ns
t _{F5-20}		1.33		1.43		1.58	ns
t _{F20+}		3.63		3.93		4.35	ns

Table 92. EP20K	600E f _{MAX} ESE	3 Timing Micr	oparameters				
Symbol	-1 Spee	d Grade	-2 Spee	ed Grade	-3 Spee	d Grade	Unit
	Min	Max	Min	Max	Min	Max	
t _{ESBARC}		1.67		2.39		3.11	ns
t _{ESBSRC}		2.27		3.07		3.86	ns
t _{ESBAWC}		3.19		4.56		5.93	ns
t _{ESBSWC}		3.51		4.62		5.72	ns
t _{ESBWASU}	1.46		2.08		2.70		ns
t _{ESBWAH}	0.00		0.00		0.00		ns
t _{ESBWDSU}	1.60		2.29		2.97		ns
t _{ESBWDH}	0.00		0.00		0.00		ns
t _{ESBRASU}	1.61		2.30		2.99		ns
t _{ESBRAH}	0.00		0.00		0.00		ns
t _{ESBWESU}	1.49		2.30		3.11		ns
t _{ESBWEH}	0.00		0.00		0.00		ns
t _{ESBDATASU}	-0.01		0.35		0.71		ns
t _{ESBDATAH}	0.13		0.13		0.13		ns
t _{ESBWADDRSU}	0.19		0.62		1.06		ns
t _{ESBRADDRSU}	0.25		0.71		1.17		ns
t _{ESBDATACO1}		1.01		1.19		1.37	ns
t _{ESBDATACO2}		2.18		3.12		4.05	ns
t _{ESBDD}		3.19		4.56		5.93	ns
t _{PD}		1.57		2.25		2.92	ns
t _{PTERMSU}	0.85		1.43		2.01		ns
t _{PTERMCO}		1.03		1.21		1.39	ns

Table 93. EP2	OK600E f _{MAX}	Routing Delays	s				
Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
t _{F1-4}		0.22		0.25		0.26	ns
t _{F5-20}		1.26		1.39		1.52	ns
t _{F20+}		3.51		3.88		4.26	ns